

**General Description**

The G1003B uses advanced trench technology to provide excellent  $R_{DS(ON)}$ , low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a load switch or in PWM applications.

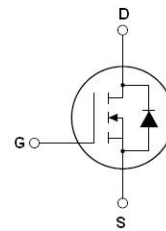
**General Features**

$V_{DSS}$	$R_{DS(ON)}$ @10V (Typ)	$R_{DS(ON)}$ @4.5V(Typ)	$I_D$
100V	135m $\Omega$	145m $\Omega$	5 A

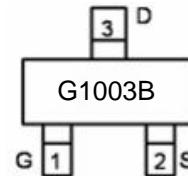
- High Power and current handing capability
- RoHS Compliant
- Surface Mount Package

**Application**

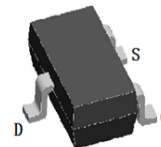
- PWM applications
- Load switch
- Power management



Schematic Diagram



Marking and pin Assignment



SOT23-3L

**Ordering Information**

Part Number	Marking	Case	Packaging
G1003B	G1003B	SOT-23-3L	3000pcs/Reel

**Table 1. Absolute Maximum Ratings (TA=25°C)**

Symbol	Parameter	Value	Unit
$V_{DS}$	Drain-Source Voltage ( $V_{GS}=0V$ )	100	V
$V_{GS}$	Gate-Source Voltage ( $V_{DS}=0V$ )	$\pm 25$	V
$I_D$	Drain Current-Continuous( $T_c=25^\circ C$ )	5	A
	Drain Current-Continuous( $T_c=100^\circ C$ )	1.8	A
$I_{DM (pluse)}$	Drain Current-Continuous@ Current-Pulsed (Note 1)	12	A
$P_D$	Maximum Power Dissipation	3.3	W
$T_J, T_{STG}$	Operating Junction and Storage Temperature Range	-55 To 150	$^\circ C$

Notes 1.Repetitive Rating: Pulse width limited by maximum junction temperature

**Table 2. Thermal Characteristic**

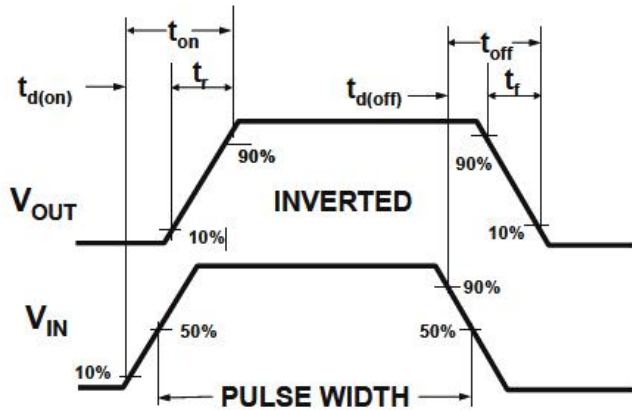
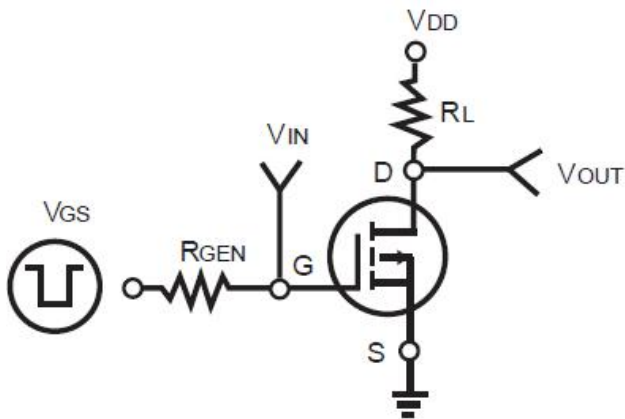
Symbol	Parameter	Typ	Value	Unit
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	-	37	$^\circ C/W$

**Table 3. Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)**

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>On/Off States</b>						
B <sub>V</sub> DSS	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	100			V
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> =100V, V <sub>GS</sub> =0V			100	μA
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V			±100	nA
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250μA	1	-	3	V
R <sub>DS(ON)</sub>	Drain-Source On-State Resistance	V <sub>GS</sub> =10V, I <sub>D</sub> =-10A		135	170	mΩ
		V <sub>GS</sub> =4.5V, I <sub>D</sub> =-5A		145	180	mΩ
<b>Dynamic Characteristics</b>						
C <sub>iss</sub>	Input Capacitance	V <sub>DS</sub> =25V, V <sub>GS</sub> =0V, f=1.0MHz		570		pF
C <sub>oss</sub>	Output Capacitance			25		pF
C <sub>rss</sub>	Reverse Transfer Capacitance			20		pF
<b>Switching Times</b>						
t <sub>d(on)</sub>	Turn-on Delay Time	V <sub>DD</sub> =15V, I <sub>D</sub> =1A, R <sub>L</sub> =15Ω V <sub>GS</sub> =10V, R <sub>G</sub> =2.5Ω		2.2		nS
t <sub>r</sub>	Turn-on Rise Time			3.9		nS
t <sub>d(off)</sub>	Turn-Off Delay Time			5.8		nS
t <sub>f</sub>	Turn-Off Fall Time			1.9		nS
Q <sub>g</sub>	Total Gate Charge	V <sub>DS</sub> =15V, I <sub>D</sub> =10A V <sub>GS</sub> =10V		30		nC
Q <sub>gs</sub>	Gate-Source Charge			6		nC
Q <sub>gd</sub>	Gate-Drain Charge			9		nC
<b>Source-Drain Diode Characteristics</b>						
I <sub>SD</sub>	Source-Drain Current(Body Diode)				12	A
V <sub>SD</sub>	Forward on Voltage(Notes 1)	V <sub>GS</sub> =0V, I <sub>S</sub> =2A			0.8	V

Notes 1. Repetitive Rating: Pulse width limited by maximum junction temperature.

Switch Time Test Circuit and Switching Waveforms:



TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS (Curves)

Figure1. Output Characteristics

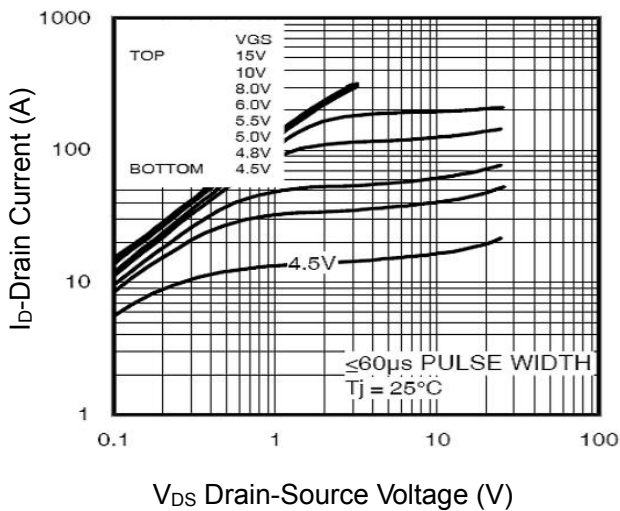


Figure2. Transfer Characteristics

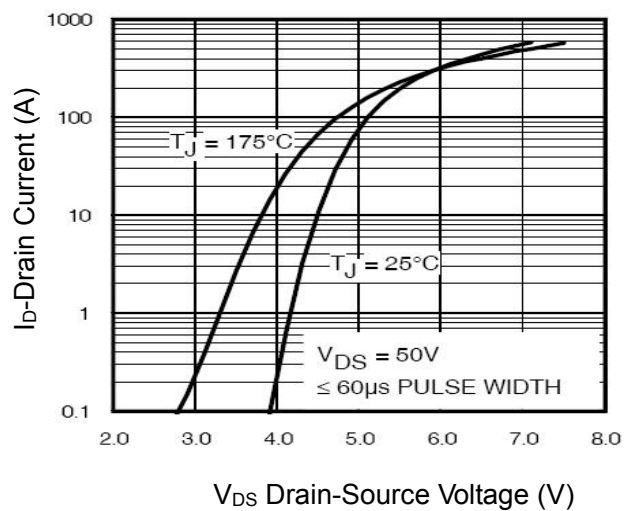


Figure3. BV<sub>DSS</sub> vs Junction Temperature

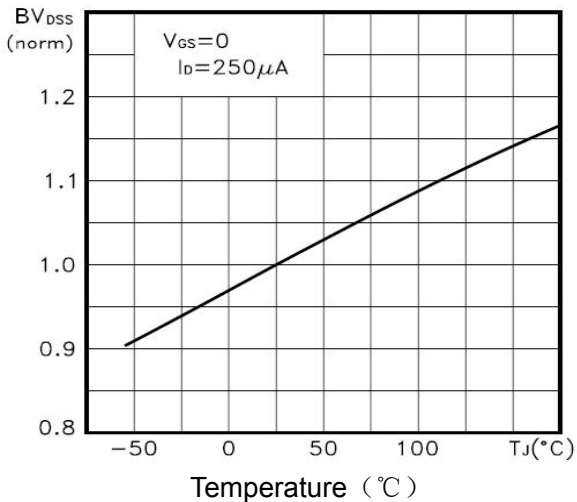


Figure4. ID vs Junction Temperature

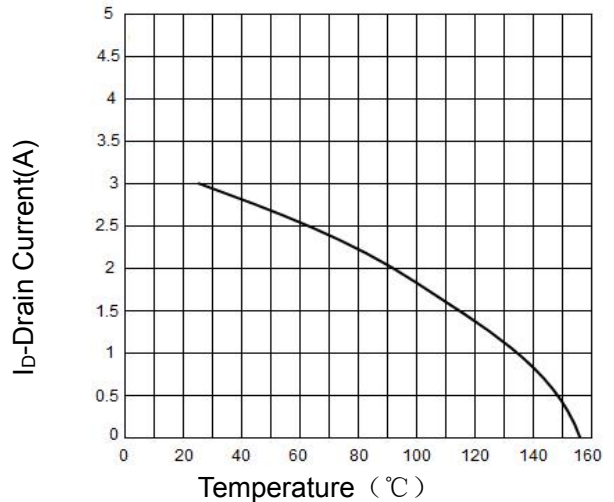


Figure5. VGS(th) vs Junction Temperature

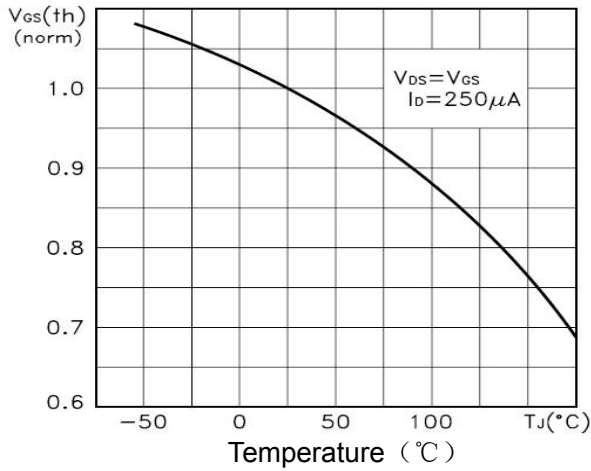


Figure6. Rds(on) Vs Junction Temperature

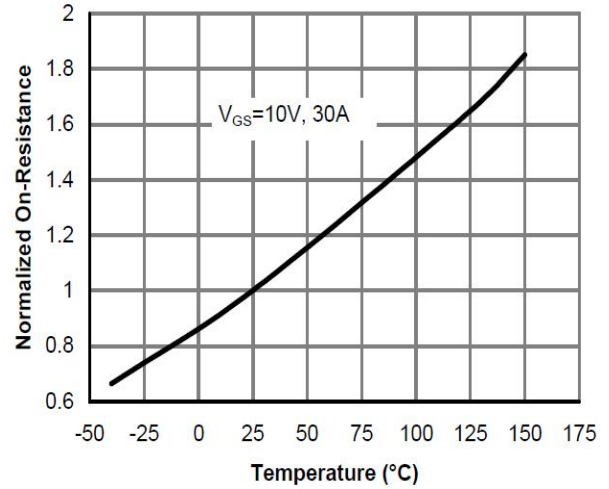


Figure7. Gate Charge

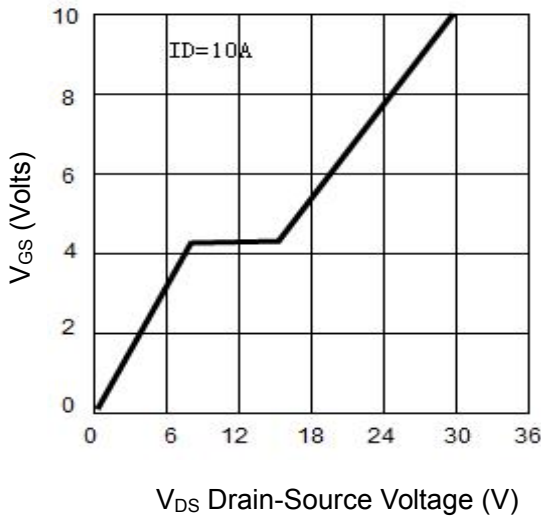


Figure8. Capacitance vs Vds

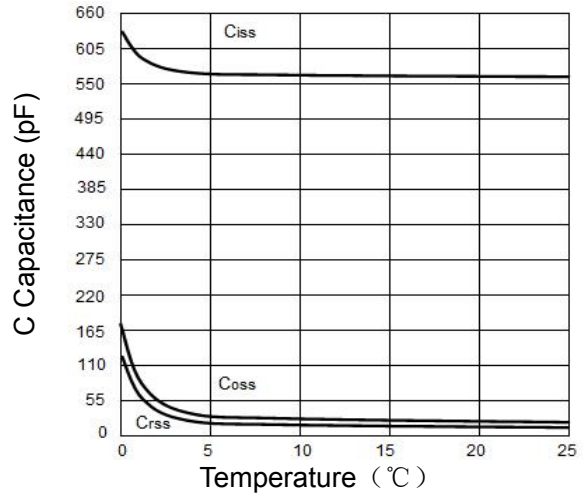


Figure9. Source- Drain Diode Forward

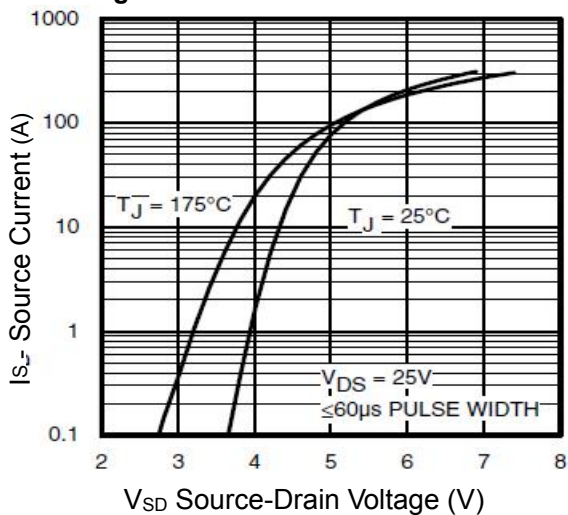


Figure10. Safe Operation Area

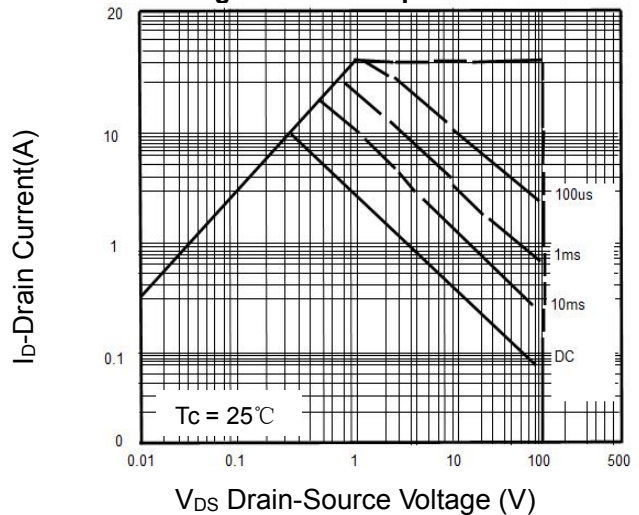
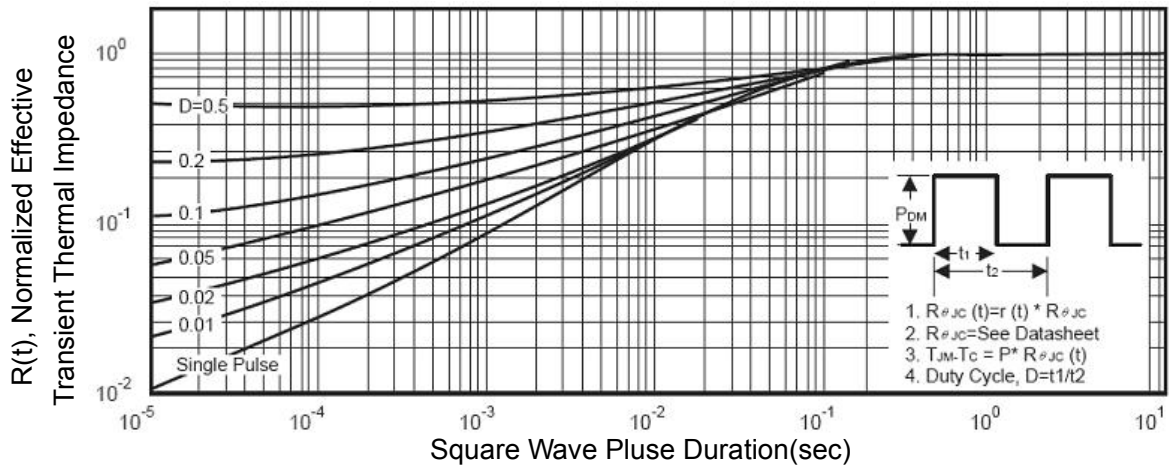
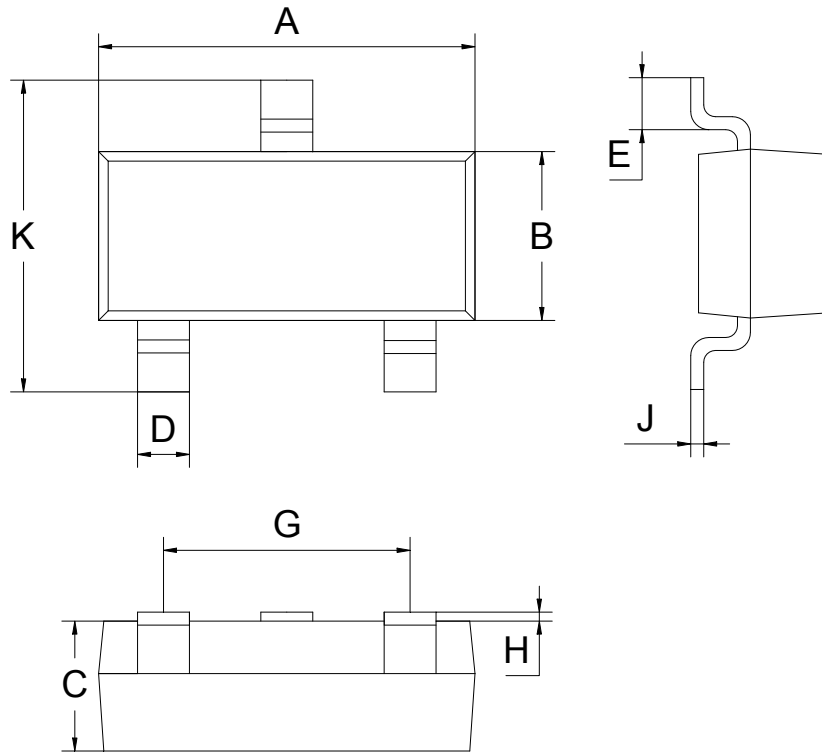


Figure11. Normalized Maximum Transient Thermal Impedance



**SOT-23-3L Package information**



SOT-23-3L			
Dim	MIN	NOM	MAX
A	2.80	2.90	3.00
B	1.50	1.60	1.70
C	1.00	1.10	1.20
D	0.30	0.40	0.50
E	0.25	0.40	0.55
G	1.90		
H	0.00	-	0.10
J	0.047	0.127	0.207
K	2.60	2.80	3.00
All Dimensions in mm			